# Plasmonic Metasurfaces with High UV-Vis Transmittance for Photopatterning of Designer Molecular Orientations

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Keywords: plasmonic metasurface, liquid crystals, photoalignments, nanomanufacturing, topological

defects

Recent developments of utilizing plasmonic metasurfaces in photopatterning of designer molecular orientations have facilitated numerous new applications of liquid crystals; while the optical efficiency of the metamasks remains a critical issue, especially in the UV region. Here we present a new design of plasmonic metasurfaces made of parallelepiped arrays that yield very high and broad-band transmission in the UV-visible wavelength range. We show that this plasmonic metamask exhibits two polarization peaks originated from a cavity mode and lattice resonance respectively and demonstrate

This is the author manuscript accepted for publication and has undergone full peer review but has not been the 19th the copyediting, typesetting, pagination and proofreading process, which may lead to differences between this version and the <u>Version of Record</u>. Please cite this article as <u>doi:</u> 10.1002/adom.201900117.

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that complex designer molecular orientations can be photopatterned by using this metamask with significantly reduced exposure time. This type of high efficiency broad-band plasmonic metasurfaces is not only important for high resolution photopatterning of molecular orientation but also tailorable for various other flat optics applications in the UV and near UV regions.

Liquid crystals are not only an intriguing subject of soft matter physics but also crucial materials for many distinctive applications such as flat panel displays. [1,2] A variety of emerging applications become possible when spatially variant molecular orientation (also called molecular director) can be controlled at will. For example, liquid crystal Pancharatnam-Berry phase optical elements such as Q-plates, lenses and beam shapers can be made to modify the orbital angular momentum, propagation direction and intensity profiles of light beams. [3–8] The stimulus-responsive deformations of liquid crystal elastomers can be preprogrammed in molecular director patterns, promising various applications in actuators and origami-inspired surfaces. [9–14] Liquid crystals with predesigned molecular director fields can enable controlling colloidal placements and assembly, [15] nonlinear electrokinetic flows [16] and commanding active matter like swimming bacteria. [17]

As the molecular director in bulk liquid crystals is set primarily by its condition at the bounding surfaces, [1] proper molecular alignment at surfaces is an essential step in liquid crystal device manufacturing. [18] Early applications and efforts were focused on uniform alignments, [18–20] while the emerging applications described above have driven rapid developments of techniques for aligning liquid crystal molecules into spatially variant directors. These techniques are based either on maskless approaches such as interference photoalignment [21] and pixel-to-pixel direct writing, [12,22,23] or on mask-based approaches such as using digital micromirror devices as a dynamic mask. [24,25]

More recently, Guo et al developed a technique for photopatterning molecular orientations by using engineered plasmonic metamasks (PMMs), in a fashion similar to projection photolithography. [26] In contrast to traditional photomasks in photolithography which generate only

light intensity patterns, the PMMs generate spatially variant patterns of polarization directions. [26] Projecting such polarization patterns onto thin films of photoalignment materials leads to reorientation of the rod-shaped molecules according to the molecular director patterns encoded in the polarization patterns of the PMMs, which can then be imposed onto liquid crystals confined by these substrates. [26] This PMM-based photopatterning significantly increases the spatial resolution and throughput in controlling molecular orientations and has facilitated various exciting new applications [8,13,15-17,27,28] However, the existing design of the PMMs suffers from low optical efficiency in the near UV wavelengths, and PMMs with high optical transmittance are still needed to match the absorption bands of various photoalignment materials.

Metasurfaces based on plasmonic and dielectric materials exhibit extraordinary capabilities in controlling the amplitude and phase profiles with subwavelength spatial resolutions. [29–38] However, efficient and robust metasurfaces working in the UV or near UV regions are still scarce, [39–43] even though they are highly desired demanded by various applications. As pointed out by Yao et al, this is limited by available material properties. Common plasmonic materials like Au and Ag are not suitable for UV due to Ohm losses; [42] UV-transparent dielectric materials suffer from low refractive indices and inter-band transitions. Several recent studies utilize metasurfaces as active or non-linear devices for UV light generation through inter-band transitions or nonlinearity property. [39–41] The only work where wavefront engineering in the UV region is based on niobium pentoxide (Nb<sub>2</sub>O<sub>5</sub>). [43]

Here we present a new design of plasmonic polarization metasurfaces with very high optical transmission as the PMMs for photopatterning complex molecular directors. As schematically shown in Figure 1a, the new PMMs are composed of rectangular parallelepipeds arranged in a triangular lattice on a fused quartz substrate. Figure 1b and 1c present representative scanning electron microscope (SEM) images of the fabricated PMMs. For convenience, we use l, w, h, p and  $\theta$  to

represent the length, width, height, periodicity and orientation of the parallelepipeds, respectively. As a trade-off between the requirement for subwavelength periodicity and the reliability of nanofabrication processes, we fixed the periodicity p and height h at 220 nm and 80 nm. By using a finite-difference time-domain (FDTD) algorithm (CST Microwave Studio Suite from CST AG), we numerically study how the optical transmission and polarization contrast are affected by the parallelepiped size, aiming to maximize the optical transmission and polarization contrast in the absorption bands of photoalignment materials such as the SD-1 (see SM) and PAAD-22 from Beamco Inc.  $^{[44]}$ 

Figure 1d-1g presents exemplary simulation results for parallelepiped arrays with p=200~nm and h=80 nm. When the incident polarization is along the short axis of the parallelepipeds (i.e. x-axis), the optical transmittance  $T_x$  increases monotonically with the wavelength for  $\lambda > 350$  nm and can reach >80% for the *i*-line wavelength (365 nm). In contrast, when the incident polarization is along the long axis of the parallelepipeds (i.e. y-axis), the optical transmittance  $T_y$  is low in the wavelength range between ~ 350 nm and ~ 550 nm. Overall the polarization-dependent optical transmissions yield a polarization contrast  $T_x/T_y$  above 10 with two peaks around 350 nm and 450 nm respectively.

The variations of the optical transmittance and the polarization contrast with the parallelepiped size are complex. As seen from Figure 1d-1e, the left polarization peak at ~350 nm is only slightly affected by the variations I, while the right polarization peak shifts to long wavelengths when I is increased or when w is decreased. The optical transmittance  $T_x$  goes up when w is decreased, but is little affected by the variation of I.

The variation of  $\theta$  exerts only little impact on  $T_x$  and  $T_x/T_y$ . Figure 2f and 2g indicate that when  $\theta$  is varied between 0° and 30°,  $T_x$  changes by less than 10%, and the polarization peaks shift by less than 10% of the peak wavelengths. To note, the PMM configurations with  $\theta$ >30° are equivalent to these with 0°< $\theta$ <30° due to the 6-fold rotational symmetry of the triangular lattice. This minimal  $\theta$  dependence is an important feature for the PMM as a robust metamask to generate complex polarization patterns.

To validate the simulation results, we fabricated the PMMs with different sizes and uniform orientations and measured their optical transmissions by using a CRAIC spectroscopy system. As shown in Figure 1h-1k, the measured  $T_x(\lambda)$  can exceed 80% at  $\lambda \sim 365$  nm (the *i*-line wavelength of mercury lamps) while exceed 90% for  $\lambda > 400$  nm. The measured  $T_y(\lambda)$  exhibit two dips, which yield two peaks in the polarization contrast spectra. Also, the position of the left polarization peak remains little changed with the variations of *I* and *w*, while the right peak shifts to longer wavelengths when *I* (or *w*) is increased (or decreased) (Figure 1h, i). Further, the optical transmittance and polarization contrast also show a robust reliability with regards to the variation of  $\theta$  (Figure 1j, k). These experimental results are in good agreements with the simulations as described above (Figure 1d-g).

The efficiency of the metamasks is determined primarily by the optical transmittance  $T_x$  for polarization along the short axes of the parallelepipeds. For PMMs with uniform orientations, the transmission spectra are similar to those of the wire grid polarizers. This is somewhat expected as the arrays of parallelepipeds can be considered as a result of cutting the Al wires. Cutting the wires into rectangular parallelepipeds leads to two dips on  $T_y$  in long wavelengths (Figure 1d-g). To elucidate the physical origins behind these dips in  $T_y$  or peaks in the polarization contrast  $T_x/T_y$ , we

extract the peak wavelengths and plot them as a function of the parallelepiped length *I* and width *w* (Figure 2a). We can see that the left peak position of polarization spectrum is minimally affected by *w* (for small *w*) but increases with the increase of *I*. The right peak shifts to longer wavelength when *I* increased and/or *w* is decreased.

We calculated the spectra of the electrical field inside the gap between two neighboring parallelepipeds and find that there exists a resonant peak in the near field spectra at the wavelength of the left polarization peak (Figure 2b) and a standing wave is formed within the gap (Fig. 2c). This indicates that the left polarization peak originates from a cavity resonance mode related to standing waves formed by the gap surface plasmons, and thus the variation with I and insensitivity with I0 or the left polarization peak are related to the dispersion dependence of the gap surface plasmon on gap size. The results for other orientation angles I0 are similar (see Fig. S2 with I0 = 30°).

The local electric fields at right peak wavelength also exhibit localizations within the air gap (Figure 2d), while no peak is observed in the near field spectra (Figure 2b). Again, the same is observed for non-zero orientation angle  $\theta$  (Fig. S2). We attribute the right polarization peak to a plasmonic lattice resonance. The parallelepipeds can be treated as electrical dipoles and the dipole moment for the i-th parallelepiped can be written as  $P_i = \alpha_0 \cdot E_i$ , where  $\alpha_0$  is the polarizability of individual parallelepiped, and the electric field  $E_i$  acting on the dipole is the sum of the incident field  $E_0$  and the electrical fields generated by the other dipoles. It can be shown that under perpendicular illumination,  $P_i = \frac{\alpha_0}{1-\alpha_0 S} E_0$ , where  $S = \sum_{i \neq j} [\frac{(1-ikr_{ij})(3cos^2\theta_{ij}e^{ikr_{ij}})}{r_{ij}^3} + \frac{k^2 sin^2\theta_{ij}e^{ikr_{ij}}}{r_{ij}}]$ . A lattice resonance occurs when  $Re(1-\alpha_0 S)=0$ . It can be shown that the S-parameter and thus the resonant wavelength is insensitive to the variation of  $\theta$  (see SM), which

explains the robustness of the right polarization peak. The variation of the right peak wavelength with w and l can also be explained as related to the dependence of  $\alpha_0$  on the size of individual parallelepipeds.

To elucidate the capability of the PMMs in generating spatially variant polarizations, we simulated parallelepipeds forming arrays of +1/2 and 1/2 defects and calculated the electrical field distribution and polarization direction at the wavelengths of the two polarization contrast peaks (Figure 3a-3b). Each simulated unit cell is made of 4 square tiles, two of which are 1/2 defects and the other two are -1/2 defects. Within each subunit of a single defect, the orientation  $\vartheta$  of the parallelepipeds is set as a linear function of the azimuthal angle  $\phi$ ,  $\theta = k\phi + \psi_0$ , where k is either 1/2 or -1/2, and  $\psi_0$  is a constant. We can see that same as the PMMs with uniform orientation, the electrical fields are localized and enhanced within the cavities between two neighboring parallelepipeds (Figure 3a, 3b). Figure 3c and 3d present calculated polarization orientations and contrasts. The spatially-variant polarization orientations of the transmitted light are primarily along the short axes of the local parallelepipeds. The polarization contrast is higher than 5 over most regions, which is sufficient for photoalignments. Meanwhile there exist polarization contrast minimums, primarily at the defect centers, which is expected as the polarization directions at these places are ill defined. This example demonstrates that this new PMM design provides simple design rule and robust control of polarization patterns.

To illustrate the performance of the new PMMs in photo-patterning designer molecular directors, we designed a PMM containing a pair of  $\pm 1/2$  and  $\pm 1/2$  topological defects. Topological defects in liquid crystals represent singularities in the molecular director fields and exhibit large gradient of the director field near the defect centers, thus they can serve as challenging testbeds for the capability and spatial resolution limit of the PMM-based photopatterning. For the  $\pm 1/2$  defect

pair, the molecular director at (x,y) is expressed as:  $\theta(x,y) = \frac{1}{2} tan^{-1} \left(\frac{y-y_{10}}{x-x_{10}}\right) - \frac{1}{2} tan^{-1} \left(\frac{y-y_{20}}{x-x_{20}}\right) + \frac{\pi}{2}$ , where  $(x_{10},y_{10})$  and  $(x_{20},y_{20})$  are the center coordinates of the 1/2 and -1/2 defects respectively. We set the orientations of the long axes of the rectangular parallelepipeds in the PMM the same as this target molecular orientations.

A representative SEM image of the fabricated pair of +1/2 (left) and -1/2 (right) defects in the PMM is shown in in Figure 3e. Non-polarized optical microscopic image of the PMM shows that the optical transmission is highly uniform (Figure 3f, upper). When the plasmonic metamask is illuminated with polarized light and observed with a cross polarization analyzer, polarizing optical microscope (POM) image show non-uniform intensity distribution (Figure 3f, lower). Considering the metamask as a polarizer with a spatially variant polarization direction, one can expected that the pixel intensity is  $\gamma \sin^2 \gamma \cos^2 \gamma$  with  $\gamma$  being the polarization orientation with respect to the polarizer. By illuminating the PMM with non-polarized light and taking images of the PMM with a polarization analyzer, we can determine the polarization direction  $\theta_0(x,y)$  at the pixel (x,y) by fitting the pixel intensity I(x,y) versus the analyzer orientation  $\theta$  with the function  $I(x,y) \sim \sin^2[\theta - \theta_0(x,y)]$ . The measured polarization directions are perpendicular to the short axes of the local parallelepipeds in the PMM (Figure 3g), which is in agreement with the design expectation.

The photopatterning of molecular orientations by using the PMM is done with a home-made projection photopatterning system (Fig. S4). Basically, the PMM is illuminated with broad-band non-polarized light, and the transmitted light becomes polarized with spatially non-uniform polarization orientation. The transmitted light is then projected onto substrates coated with photoalignment material such as SD-1. Illumination of polarized light causes the rod-shaped SD-1

molecules to reorient themselves to have their dipoles (i.e. long molecular axes) perpendicular to the polarization directions. As a result, the polarization pattern is converted into the orientation pattern of the SD-1 molecules. When other liquid crystal molecules such as RM-257 are spin-coated on the SD-1 films, they will follow the orientations of the SD-1 due to molecular interactions. This process is very similar to the projection photolithography except that the PMM generates polarization patterns instead of intensity patterns and the photo-exposure cause molecular reorientation instead of photochemical reactions (leading to microstructures).

Figure 3h and 3i represent polarized microscopic and PolScope images of a photopatterned sample of liquid crystal polymers fabricated according to the photopatterning processes described in the Experimental session. It can be seen that that the molecular orientations are the same as those of the parallelepipeds in the PMM in Figure 3e and that the phase retardation is highly uniform, demonstrating its high performances in photopatterning and in-plane alignment of the LC molecules. This also demonstrates extremely simple design rules to the PMMs, i.e. orienting the parallelepipeds according exactly to desired molecular orientations.

To quantify the performance of the new PMM in photopatterning, we did dose tests to compare this new parallelepiped-based PMMs with the prior nanoaperture-based PMMs (Figure 4). The optical transmissions of the nanoaperture-based PMMs are primarily located above 400 nm (see SM, Fig. S5). When the X-Cite 120 light source is used at its maximal intensity output and the projection system works at 1.1 magnification, the required exposure time is less than 1s for both types of PMMs. Therefore, to facilitate an accurate comparison, we used the lowest output intensity of the light source and set projection magnification to 2.5. Fig. 4a-4b and Fig. 4e-4f present POM and PolScope images of polymerized RM-257 films on SD-1 photopatterned with the new PMM; and Fig. 4c-4d and Fig. 4g-4g present the POM and PolScope images of polymerized RM-257 films on SD-1

photopatterned with a prior PMM based on rectangular hole arrays in Al films. The noises in the polarizing optical microscope images in Fig. 4a-d indicate that the liquid crystal molecules are not fully aligned, and that the degree of alignments fluctuates spatially. The phase retardation measured by the PolScope is defined as  $\delta=(n_e-n_o)t$  where  $n_e$ , and  $n_o$ , are the refractive index for polarization parallel and perpendicular the molecular axis, and t is the film thickness. When all molecular are all aligned,  $(n_e-n_o)$  maximizes. Therefore, longer exposure times lead to less noises in the POM larger and larger phase retardations, or higher degrees of molecular alignments.

Under the same illumination intensity and projection magnification, we found that at least 80 s is needed for the old nanoaperture-based PMMs to achieve smooth molecular orientation patterns (Figure 4d, 4h). In contrast, the parallelepiped-based PMM only needs 20 s (Figure 4b, 4f). This demonstrates that a significant reduction (~75%) in the exposure time is achieved by using the new PMMs.

In conclusion, we have demonstrated plasmonic metasurfaces consisting of arrays of Al rectangular parallelepipeds which can serve as UV metamasks for photo-patterning of designer molecular orientations with very high optical efficiency. By numerical simulations, we show that such plasmonic metamasks exhibit two peaks in their polarization contrast spectra due respectively to the cavity and fattice resonances and that the central wavelengths of these two peaks are minimally affected by varying the parallelepiped orientation, making them very robust in polarization control. We show that photopatterning with this new type of metamasks significantly reduce the exposure time. Though not shown here, it can also be expected that photopatterning with UV light can increase its spatial resolution. Further, we like to point out that the Al-based metasurfaces are actually quite stable overtime, because the thin aluminum oxide on the Al surfaces is able to protect Al from further oxidation.

It is important to note that the optical efficiency of the Al parallelepiped metasurfaces is equivalent to that of dielectric metasurfaces. In comparison to the high aspect ratios (~10:1) required by dielectric metasurfaces, the low aspect ratio of the parallelepipeds (~1:1) make the Al metasurface easy to fabricate. In addition, though the data presented in this paper are for fixed parallelepiped height and periodicity, we did simulations with other heights and periodicities. The numerical results can show that by varying the size of the parallelepipeds, the polarization peaks can be further tuned at least down to 300 nm. It can be expected that such Al plasmonic metasurfaces find many applications in flat optics in the UV region, including meta-lenses, meta-holograms and meta-gratings.

### **Experimental Section**

Numerical simulations: The optical properties of the PMMs were numerically modeled by using the commercial software CST MICROWAVE STUDIO. Hexahedral mesh scheme was used with small mesh sizes (≤ 10 nm, much smaller than the surface resonance wavelength). The thickness of the fused quartz substrate was set as infinity, and the size (length, width and height) and periodicity of the parallelepipeds were varied according to the designs. The PMMs were illuminated from the quartz substrates side. The distributions of the electrical and magnetic fields at a plane of 420 nm above the PMM was collected to calculate the transmission spectra.

Fabrication of the PMMs: A 80 nm Al film and a 40 nm SiO<sub>2</sub> film were sequentially deposited on fused quartz substrates by sputtering deposition, then a 100 nm Al film was deposited and patterned to cover the SiO<sub>2</sub> film except the areas for the PMM patterns by

photolithography, Al deposition and a lift-off process. These substrates were then spin-coated with e-beam resist and patterned with e-beam writing. After resist development, a 25 nm Al film-was deposited and lift-off, the mask patterns were then transferred into the SiO<sub>2</sub> layers and then to the Al layer through reactive ion etching (RIE).

Projection photopatterning system: An optical setup was home-built for projection photopatterning liquid crystal molecular orientations, and details were published in a prior paper. A schematic of the setup is shown in Fig. S4. A non-polarized white light source, the X-Cite series 120, is used to illuminate the PMMs. After passing through the PMMs, light with spatially variant polarization patterns is generated and then collected by an NUV imaging objective (obj1) and projected onto the glass substrate coated with photoalignment materials by using the projection objective (obj2). The magnification of the projection setup is determined by the ratio between the magnifications of the imaging objective and projection objective.

Photopatterning process: Cleaned glass slides were spin-coated with sulfuric dye 1 (SD-1, 0.4wt% in dimethylformamide) with a 3000rpm spin speed and then baked on a hot plate at 85°C for 20 minutes. These glass slides with coated SD-1 films were exposed by using the projection photopatterning system, with the exposure time depending on the light intensity of light source and the magnification. On these slides with photopatterned SD-1, toluene solutions of the LC Monomer RM257 (10 wt%) and Irgacure 651 photo initiator (5 wt% of RM257) were spin-coated to at 3000rpm for 40s. After a 15 min photo-polymerization with UV illumination, the photo-patterned orientations of the SD-1 molecules were transferred to the RM257 molecules and then fixed by photopolymerization process.

Optical characterization: The PolScope technique is used to accurately map out the molecular orientation in patterned LC films. The PolScope illuminates samples with a monochromatic polarized light ( $\lambda$  = 546 nm) at different polarization orientations and allows for measuring spatially variant optical retardance and slow axis of birefringent materials. For nematic LC materials with positive  $\Delta n$ , the slow axis is simply the long axis of the rod-shaped LC molecules.

### **Supporting Information**

Supporting Information is available from the Wiley Online Library or from the author.

## Acknowledgements

Hao Yu and Miao Jiang contributed equally to this work. This work was supported by NSF through CMMI-1663394 and CMMI-1436565. The author QHW also acknowledges the financial support by the AvH foundation and Clemens Bechinger for his hospitality of during his sabbatical in Univ. Konstanz when this manuscript was prepared.

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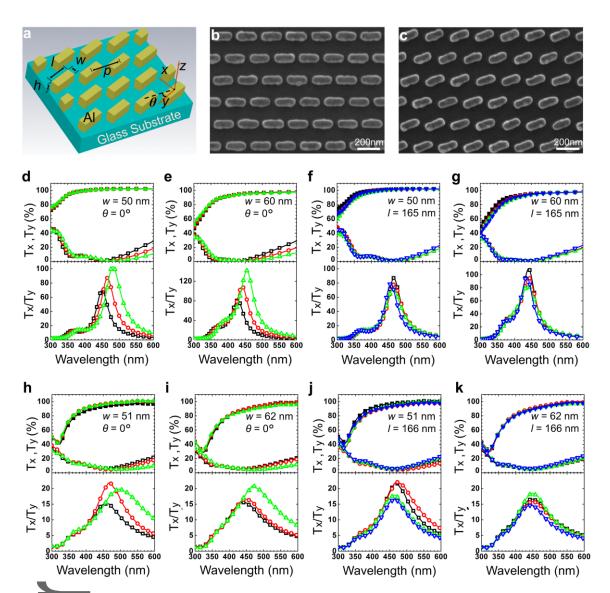
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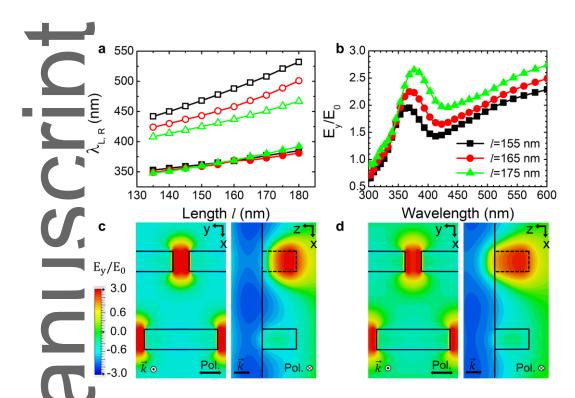
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**Figure 1** Simulation and experimental results for the PMM with uniform orientation. a) Schematic PMM comprised of rectangular parallelepipeds arranged in a triangular lattice. b, c) SEM images of two representative PMMs with  $\theta = 0^{\circ}$  in b) and  $20^{\circ}$  in c). d, e) Optical transmittance (top) and polarization contrast (bottom) for I = 155 nm (black square), 165 nm (red circle), 175 nm (green triangle), w = 50 nm in a and 60 nm in b, and  $\theta = 0^{\circ}$ . f, g). Optical transmittance and polarization contrast for  $\theta = 0^{\circ}$  (black square),  $10^{\circ}$  (red circle),  $20^{\circ}$  (green up triangle),  $30^{\circ}$  (blue down triangle), w = 50 nm in c and 60 nm in d, and I = 165nm. h, i) Measured optical transmittance (top) and polarization contrast (bottom) for I = 156 nm (black square), 166 nm (red circle), 175 nm (green triangle), w = 51 nm in d and 62 nm in e, and  $\theta = 0^{\circ}$ . j, k) Measured optical transmittance and polarization contrast for  $\theta = 0^{\circ}$  (black square),  $10^{\circ}$  (red circle),  $20^{\circ}$  (green up triangle),  $30^{\circ}$  (blue down triangle), w = 50 nm in f and 60 nm in g, and I = 1000 (blue down triangle),  $00^{\circ}$ 0 (blue down triangle),  $00^{\circ}$ 1 (blue down triangle),  $00^{\circ}$ 2 (blue down triangle),  $00^{\circ}$ 3 (blue down triangle),  $00^{\circ}$ 4 (blue down triangle),  $00^{\circ}$ 5 (blue down triangle),  $00^{\circ}$ 6 (blue down triangle),  $00^{\circ}$ 7 (blue down triangle),  $00^{\circ}$ 8 (blue down triangle),  $00^{\circ}$ 9 (blue down triangle)





**Figure 2.** a) Calculated center wavelengths of the left (solid data points) and right (open data points) peaks in the polarization contrasts versus the parallelepiped length I for different parallelepiped widths: w = 40 nm (black square), 50 nm (red circle) and 60 nm (green triangle). Here  $\theta = 0^{\circ}$ . b) Calculated local electric field enhancement as a function of wavelength at the top center of the gap between two neighboring parallelepipeds. Here p, h and  $\theta$  are fixed at 220 nm, 80 nm and  $0^{\circ}$  respectively. c, d) Snapshots of the local electrical field distributions, at two resonant wavelengths, c) 375nm and d) 480 nm respectively. The incident polarization is along the y-axis, and I=180 nm, I=80 nm, I=80

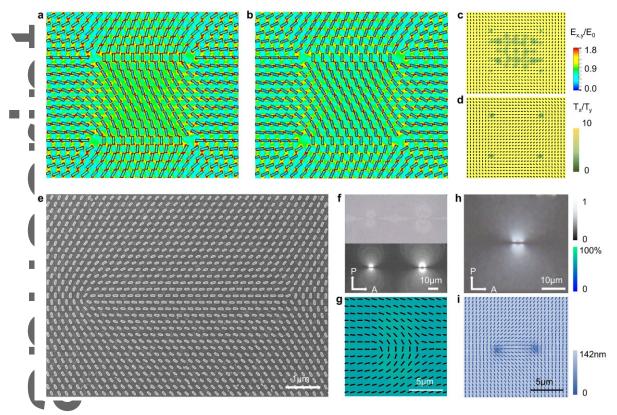
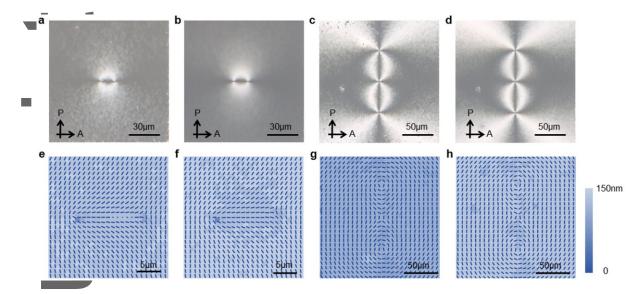


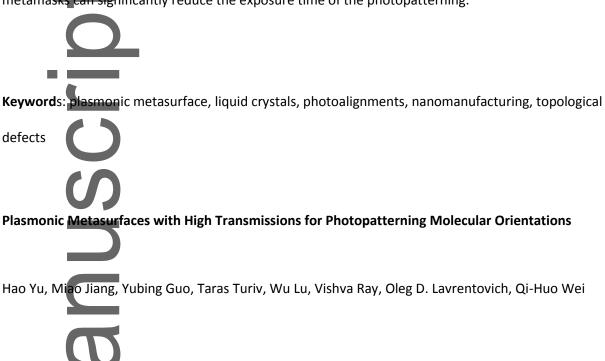
Figure 3. Simulations and photopatterning for PMMs with spatially variant polarizations. a-b) Simulated near field distribution and polarization orientation at the peak wavelength  $\lambda$ =375 (a, c) and the peak wavelength  $\lambda$ =480nm (b, d). The parallelepiped size and period: I = 180 nm, h = 80 nm, w = 50 nm, p = 220 nm. The calculated electrical field is at a plane 420 nm above the parallelepipeds. (e) A SEM image of the PMM with a ± ½ defect pair. (f) Transmission optical microscopic images without (top) and with crossed polarizers (bottom) for the fabricated PMM with two pairs of ± ½ defects, the defect spacing is 6  $\mu$ m and 8  $\mu$ m, respectively. (g) Measured polarization pattern for the PMM, where the background color represents the optical transmittance. (h, i) POM and PolScope images of a LC polymer sample photopatterned with the PMM with one defect pair, where blue lines represent molecular orientation and background color the local phase retardation. Arrows P and A in (f) and (g) represent the orientation of polarizer and analyzer in POM. The color scale bars, from top to bottom on the right side, represent local field enhancements, polarization contrast ( $T_x/T_y$ ), the optical transmittance and phase retardation in (a, b), (c, d), (g) and (i) respectively. The grey scale bar represents normalized light intensity for individual pixels for (f, bottom).





**Figure 4** A comparison of exposure time between the parallelepiped-based and prior nanoaperture-based PMMs. a-d) representative POM images of the LC films photopatterned with the parallelepiped-based PMMs with: a) 10s and b) 20 s exposure times, and the nanoaperture-based PMM with: c) 70s and d) 80 s exposure time. e-h) Corresponding Polscope images of the photopatterned LC films in a-d), where the background color represents phase retardation and the lines represent molecular orientations. A and P in (a-d) indicate the orientations of the polarizer and analyzer in the microscope.

Spatially variant molecular orientations are central to many liquid crystal applications. Here we present a new design of plasmonic metasurfaces with ultrahigh optical transmissions as metamasks for photopatterning arbitrary designer molecular orientations and demonstrate that such metamasks can significantly reduce the exposure time of the photopatterning.



Plasmonic Metasurfaces with High UV-Vis Transmissions for Photopatterning of Arbitrary Designer Molecular Orientations

